Amendments to the Claims:

The following listing of claims will replace all prior versions, and listings, of claims in the application:

- 1-14. (Canceled).
- 15. (Currently Amended) An electroluminescent device, comprising:a bank defining a pixel;an anode provided for the pixel;

a light-emitting layer provided in the pixel and above the anode and including at least an organic polymer;

a thin-film layer provided on above the light-emitting layer for suppressing current flowing through the light-emitting layer and not contributing to light emission and overlapping the bank; and

a cathode provided on above the thin-film layer, the cathode overlying overlapping the bank and the bank overlying edges of the anode.

- 16. (Canceled).
- 17. (Currently Amended) The electroluminescent device according to claim 15, the thin-film layer including at least one material selected from the group consisting of a fluoride or an oxide of an alkali metal, a fluoride or an oxide of an alkaline earth metal, and a fluoride or an oxide of a group III element in the periodic table suppressing current flowing through the light-emitting layer and not contributing to light emission.
 - 18. (Canceled).
- 19. (Currently Amended) The electroluminescent device according to claim 15,the thin-film layer being disposed only between the anode and the light-emitting layer the bank overlapping edges of the anode.

20. (Original) The electroluminescent device according to claim 15, further comprising:

a hole injection layer having electrical conductivity, the thickness thereof being not less than 100 nm, disposed between the light-emitting layer and the anode.

21. (Original) The electroluminescent device according to claim 15, further comprising:

a buffer layer having electrical conductivity, the thickness thereof being not less than 100 nm, disposed between the light-emitting layer and the anode.

- 22. (Original) The electroluminescent device according to claim 15, the organic polymer including at least one of polyfluorene and a derivative of polyfluorene.
- 23. (Original) The electroluminescent device according to claim 15, the organic polymer including at least one of poly(p-phenylenevinylene) and a derivative of poly(p-phenylenevinylene).
- 24. (Original) The electroluminescent device according to claim 15, the degree of polymerization of the organic polymer being at least two.
- 25. (Original) The electroluminescent device according to claim 15, the lightemitting layer being formed by depositing a plurality of light-emitting material layers.
- 26. (Original) The electroluminescent device according to claim 15, the lightemitting layer including the organic polymer being formed by a printing method.
- 27. (Original) The electroluminescent device according to claim 26, the printing method being an ink-jet method.
- 28. (Currently Amended) An <u>electronic device having an electroluminescent</u> device, <u>the electroluminescent device comprising</u>:

a bank defining a plurality of pixels;

a plurality of anodes, each of the plurality of anodes being provided for each of the plurality of pixels;

a plurality of light-emitting layers, each of the light emitting layers being provided in each of the plurality of pixels and the above each of the plurality of anodes and including at least an organic polymer;

a thin-film layer commonly provided on above the plurality of light-emitting layers for suppressing current flowing through the plurality of light-emitting layers and not contributing to light-emission and overlapping the bank; and

a cathode provided on above the thin-film layer, the cathode overlying overlapping the bank and the bank overlying edges of the plurality of anodes.

- 29. (Canceled).
- 30. (Currently Amended) The electroluminescent electronic device according to claim 28, the thin-film layer including at least one material selected from the group consisting of a fluoride or an oxide of an alkali metal, a fluoride or an oxide of an alkaline earth metal, and a fluoride or an oxide of a group III element in the periodic table suppressing current flowing through the light-emitting layer and not contributing to light emission.
 - 31. (Canceled).
- 32. (Currently Amended) The electroluminescent electronic device according to claim 28, the thin-film layer being disposed only between the anode and the light emitting layer the bank overlapping edges of the plurality of anodes.
- 33. (Currently Amended) The electroluminescent electronic device according to claim 28, further comprising:

a hole injection layer having electrical conductivity, the thickness thereof being not less than 100 nm, disposed between the light-emitting layer and the anode. 34. (Currently Amended) The electroluminescent electronic device according to claim 28, further comprising:

a buffer layer having electrical conductivity, the thickness thereof being not less than 100 nm, disposed between the light-emitting layer and the anode.

- 35. (Currently Amended) The electroluminescent electronic device according to claim 28, the organic polymer including at least one of polyfluorene and a derivative of polyfluorene.
- 36. (Currently Amended) The <u>electroluminescent_electronic</u> device according to claim 28, the organic polymer including at least one of poly(p-phenylenevinylene) and a derivative of poly(p-phenylenevinylene).
- 37. (Currently Amended) The electroluminescent electronic device according to claim 28, the degree of polymerization of the organic polymer being at least two.
- 38. (Currently Amended) The electroluminescent electronic device according to claim 28, the light-emitting layer being formed by depositing a plurality of light-emitting material layers.
 - 39. (Canceled).
- 40. (Currently Amended) The electroluminescent electronic device according to claim 28, the printing method being an ink-jet method.
 - 41-42. (Canceled).